

EVHR1203-Y-00A

240W General-Purpose Evaluation Board

DESCRIPTION

The EVHR1203-Y-00A is a general-purpose evaluation board for the HR1203 for 240W PC and ATX power, adapters, all-in-one or gaming power, and general AC/DC power supply applications.

The HR1203 integrates a digital PFC controller and a half-bridge resonant controller into a single chip. It uses very low power at no load or ultra-light load, making it compliant with Energy Using Product Directive (EuP) Lot 6 and Code of Conduct Version 5 Tier 2 specifications.

The PFC of the HR1203 employs a patented average current control scheme, which can operate in continuous conduction mode (CCM) and discontinuous conduction mode (DCM), according to the instantaneous condition of the input voltage and output load. The IC exhibits excellent efficiency and a high power factor (PF) at light load.

The half-bridge LLC converter achieves high efficiency with zero-voltage switching (ZVS). The HR1203 implements an adaptive dead-time adjustment (ADTA) function so the LLC converter can easily achieve ZVS from heavy load to light load. Additionally, the HR1203 can prevent the LLC converter from operating in capacitive mode, making it more robust and easier to design.

Typically, the EVHR1203-Y-00A is designed for PC and ATX power, adapters, and gaming power applications with a 12V, 20A constant voltage output and 240W rated power from $90V_{AC}$ to $265V_{AC}$ and 50Hz/60Hz.

The EVHR1203-Y-00A has excellent efficiency and a high power factor for the entire load range. Full protection features include overload protection, short-circuit protection (SCP), overvoltage protection (OVP), and anti-capacitive mode protection. The EVHR1203-Y-00A also meets the Class C standard of IEC61000-3-2 and the EN55022 standard.

ELECTRICAL SPECIFICATIONS

Parameter	Symbol	Value	Units
Input AC voltage	V _{IN_AC}	90 to 265	V
Output current	louт	20	Α
Output voltage	Vout	12	V
Output power	Роит	240	W

FEATURES

- Wide Operating Input Range (from 90V to 265V)
- 240W Rated Power and Constant Voltage Output
- High Efficiency Up to 93%
- Meets EuP Lot 6 and COC Version 5 Tier 2 **Specifications**
- Meets Class C Standard of IEC61000-3-2
- Meets EN55022 Standard
- Meets EN61000-4-5 Level 4 for Surge Immunity (4kV)
- High Power Factor (PF)
- Overload Protection (Auto-Restart Mode)
- Short-Circuit Protection (SCP) (Auto-Restart Mode)
- Over-Voltage Protection (OVP)
- Anti-Capacitive Mode Protection

APPLICATIONS

- PC and ATX Power
- Adapters
- All-in-One or Gaming Power Supplies
- General AC/DC Power Supply

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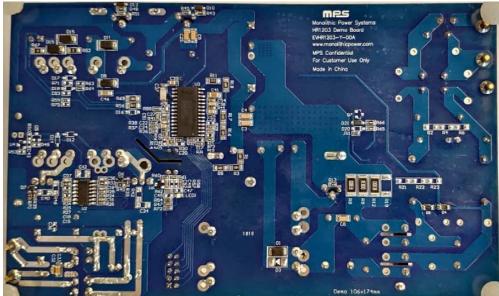
Warning: Although this board is designed to satisfy safety requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide AC input to the igh Voltage prototype board.

EVHR1203-Y-00A Rev. 1.0 www.MonolithicPower.com 6/12/2019



EVHR1203-Y-00A EVALUATION BOARD



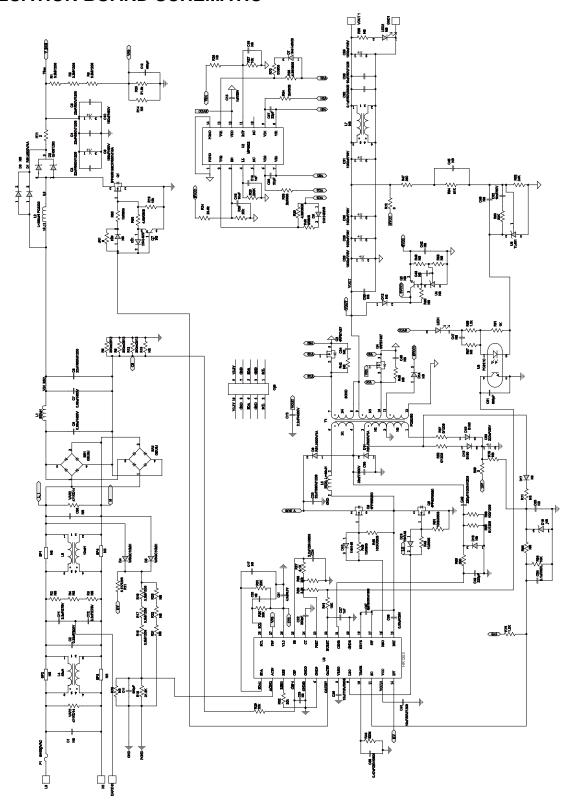


(LxWxH) (17.4cmx10.55cmx3.5cm)

Board Number	MPS IC Number
EVHR1203-Y-00A	HR1203GY
EVHR 1203-1-00A	MP6922DS



EVALUATION BOARD SCHEMATIC





EVHR1203-Y-00A BILL OF MATERIALS

Qty	Ref	Value	Description	Package	Manufacturer	Manufacturer P/N
2	CY1, CY2	3.3nF	Y capacitor, 2600V, 20%	DIP	HongKe	JYK10F332MY72N
1	CY3	2.2nF	Y capacitor, 4000V, 20%	DIP	HongKe	JNK12E222MY02N
5	C28, C29, C30, C31, C59	1000µF	Electrolytic capacitor, 16V	DIP	JIANGHAI	C287-16V1000
1	C2	0.33µF	X-capacitor, 310V	DIP	VISHAY	BFC233920334
2	C6, C7	0.68µF	Capacitor, 450V, CBB	DIP	CARLI	TF684K2Y10BL270D9R
5	C3, C4, C5, C8, C25	22nF	Ceramic capacitor, 630V, X7R	1206	TDK	
1	C15	1µF	Ceramic capacitor, 25V, X7R	0603	Murata	GRM188R71E105KA12D
2	C9, C10	180µF	Electrolytic capacitor, 450V	DIP	JIANGHAI	CD263-450V180
3	C11, C12, C51	680pF	Ceramic capacitor, 50V, X7R	0603	Murata	GRM188R71H681KA01D
2	C19, C27	1nF	Ceramic capacitor, 50V, X7R	0603	Murata	GRM188R71H102KA01D
1	C54	0.1µF	Ceramic capacitor, 50V, X7R	0603	Murata	GRM188R71H104KA93D
1	C39	0.33µF	Ceramic capacitor, 50V, X7R	0805	TDK	C2012X7R1H334K
1	C22	330pF	Ceramic capacitor, 50V, COG	0603	TDK	C1608COG1H331D
1	C48	220pF	Ceramic capacitor, 50V, COG	0603	Murata	GMR1885C1H221JA01D
1	C37	5pF	Ceramic capacitor, 3000V, NP0	1808	HHEC	C1808N5R0J302T
2	C16, C52	10nF	Ceramic capacitor, 50V, X7R	0603	Murata	GRM188R71H103KA01D
1	C21	4.7μF	Ceramic capacitor, 6.3V, X5R	0603	TDK	C1608X5R0J475K
1	C32	0.1µF	Ceramic capacitor, 50V, X7R	0805	TDK	C2012X7R1H104K
1	C35	33nF	Capacitor, 1000V	DIP	FaLa	MMKP82-1000V-333P15JA
1	C38	0.47µF	Ceramic capacitor, 25V, X7R	0805	Murata	GMR21BR71E474KA01L
2	C33, C41	10µF	Ceramic capacitor, 50V, X5R	1206	Murata	GRM31CR61H106KA12L
1	C26	10µF	Ceramic capacitor, 16V, X7R	0805	Murata	GMR21BR61C106KE15
1	C46	220pF	Ceramic capacitor, 1000V, U2J	1206	Murata	GMR31A7U3A221JW31D
1	C50	220µF	Electrolytic capacitor, 35V	DIP	JIANGHAI	CD110-35V220
1	C24	2.2µF	Ceramic capacitor, 25V, X7R	0805	Murata	GRM21BR71E225KA73L



EVHR1203-Y-00A BILL OF MATERIALS (continued)

Qty	Ref	Value	Description	Package	Manufacturer	Manufacturer P/N
2	C56, C57	22pF	Ceramic capacitor, 50V, COG	0603	TDK	C1608COG1H220J
3	R35, R39, R66	4.99Ω	Film resistor, 1%	0805	Yageo	RC0805FR-074R99L
6	R26, R29, R30, R31, R32, R36	20kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-0720KL
6	R1, R3, R5, R16, R17, R18	3.3ΜΩ	Film resistor, 1%	1206	Yageo	RC1206FR-073M3L
1	R11	5.1kΩ	Film resistor, 1%	1206	Yageo	RC1206FR-075K1L
2	R33, R34	4.99kΩ	Film resistor, 1%	0805	Yageo	RC0805FR-074K99L
2	R58, R76	1.2kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-071K2L
3	R28, R45, R51	100kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-07100KL
1	R24	24.9kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-0724K9L
3	R43, R48, R65	10Ω	Film resistor, 1%	0805	Yageo	RC0805FR-0710RL
1	R60	30kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-0730KL
3	R8, R9, R12	0.3Ω	Film resistor, 1%	2512	Yageo	RL2512FK-070R3L
1	R37	5.1kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-075K1L
4	R13, R27, R41, R64	10kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-0710KL
2	R15, R20	31.6kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-0731K6L
1	R44	820kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-07820KL
1	R61	1kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-071KL
2	R47, R55	200Ω	Film resistor, 1%	0603	Yageo	RC0603FR-07200RL
1	R38	3.3kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-073K3L
2	R52, R67	0Ω	Film resistor, 5%	1206	Yageo	RC1206JR-070RL
3	R59, R72, JR1	0Ω	Film resistor, 5%	0603	Yageo	RC0603JR-070RL
2	R40, R70	0Ω	Film resistor, 5%	0805	Yageo	RC0805JR-070RL
1	R54	91kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-0791KL
1	R56	51Ω	Film resistor, 1%	1206	Yageo	RC1206FR-0751RL
1	R69	100Ω	Film resistor, 1%	1206	Yageo	RC1206FR-07100RL
1	R62	24kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-0724KL
1	RT1	2Ω	Thermal resistor	DIP	Semitec	2D2-10
2	VAR1, VAR2	471KD 14	MOV	DIP	TKS	TVR14471KS42Y
1	BR1	GBU8J	Bridge rectifier, 600V, 8A	DIP	Diodes	GBU8J
3	D1, D8, D11	RS1J	Diode, 600V, 1A	SMA	Diodes	RS1J
1	D2	QH08T Z60	Diode, 600V, 8A	TO-220	PI	QH08TZ60



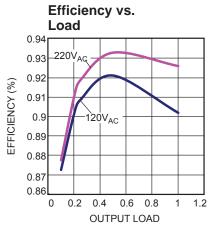
EVHR1203-Y-00A BILL OF MATERIALS (continued)

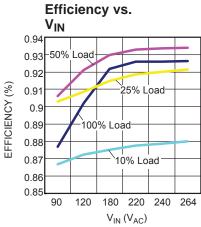
Qty	Ref	Value	Description	Package	Manufacturer	Manufacturer P/N
2	D4, D5	WSGC10MH	Diode, 1000V, 1A	1206	ZOWIE	WSGC10MH
2	D6, D7	1N4148WS	Diode, 75V, 0.15A	SOD-323	Diodes	1N4148WS
3	D10, D13, D21	1N4148W	Diode, 75V, 0.15A	SOD-123	Diodes	1N4148W
2	D15, D19	B160	Schottky diode, 60V, 1A	SMA	Diodes	B160
1	F1	5A/300VAC	FUSE-SS-5H	DIP	COOPER BUSSMANN	SS-5H-5A
1	L4	42µH	Common choke, 42µH, 6.5A	DIP	Wurth	744842742
1	L1	300µH	Filter inductor, 300µH, 3A	DIP	Wurth	7447065
1	L5	10mH	Common choke, 10mH, 5A	DIP	Wurth	744825510
1	L2	260µH	PFC inductor, L = 260µH, PQ3230	DIP	Emei	FX0432
1	L6	80μΗ	Resonant inductor, EE20	DIP	Emei	FX0430
2	L7	Jumper wire	Jumper wire instead	DIP		
1	Q1	IPP60R199CP	N-channel MOSFET, 650V, 16A	TO220	Infineon	IPP60R199CP
2	Q3, Q6	IPP65R380E	N-channel MOSFET, 700V, 29A	TO220	Infineon	IPP65R380E6
2	Q2, Q4	IRFB7437	N-channel MOSFET, 40V, To-220	TO220	IR	IRFB7437
1	T1	0.65mH	Transformer, L _P = 0.65mH, N1:N2:N3:N4:N5 = 48:5:5:3:3, PQ3230	DIP	Emei	FX0433
1	U3	HR1203	PFC + LLC COMBO controller	SOIC28	MPS	HR1203GY
1	U6	TL431	Shunt regulator, V _{REF} = 2.5V	SOT-23	Changjiang Electronics	TL431
1	U5	PC817C	Photocoupler, single- channel	DIP	SHARP	PC817C
1	U2	MP6922	SR controller	SOIC8	MPS	MP6922DS-LF-Z
1	LED1	HL-PSC- 2012H203BC	LED, blue	0805	BRIGHT LED	HL-PSC- 2012H203BC
5	VOUT, GND, L, N, Earth		2mm connector pin			
1	HS1					
1	HS2					
1	HS3					
1	HS4					
1	CN2		Connector 2*5			
1	PCB		EVHR1203-Y-00A			

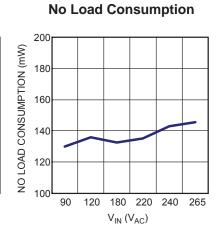


EVB TEST RESULTS

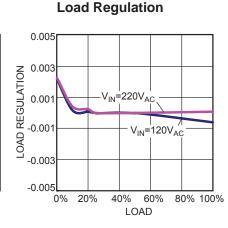
Performance waveforms are tested on the evaluation board. V_{IN_AC} = 90V to 265V, V_{OUT} = 12V, I_{OUT} = 20A, P_{OUT} = 240W

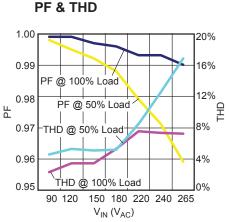


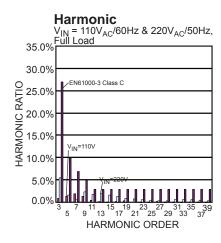




Line Regulation 0.005 0.004 0.003 0.003 0.002 0 0.001 0 0.001 10% Load 25% Load -50% Load -0.002 00% Load -0.003 -0.004 -0.005 120 180 220 90 240 264 V_{IN} (V_{AC})







I_L_{PFC} 2A/div.

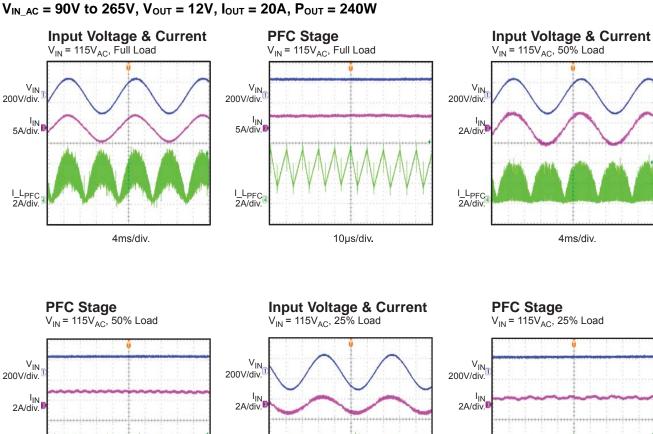
20µs/div.

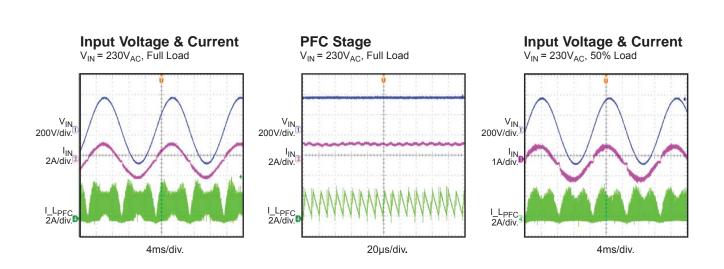


EVB TEST RESULTS (continued)

20µs/div.

Performance waveforms are tested on the evaluation board.





4ms/div.

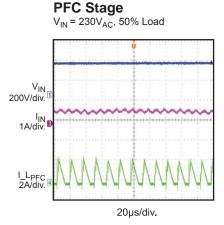
I_L_{PFC} 2A/div.

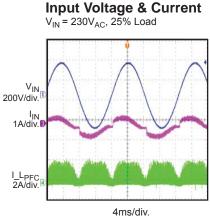
I_L_{PFC} 2A/div.

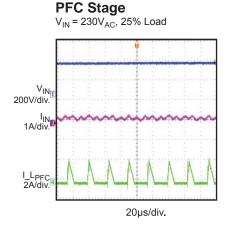


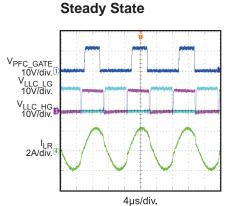
EVB TEST RESULTS (continued)

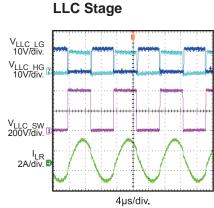
Performance waveforms are tested on the evaluation board. V_{IN_AC} = 90V to 265V, V_{OUT} = 12V, I_{OUT} = 20A, P_{OUT} = 240W

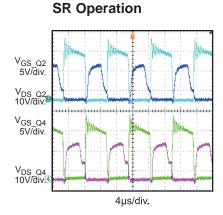




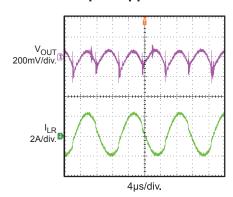








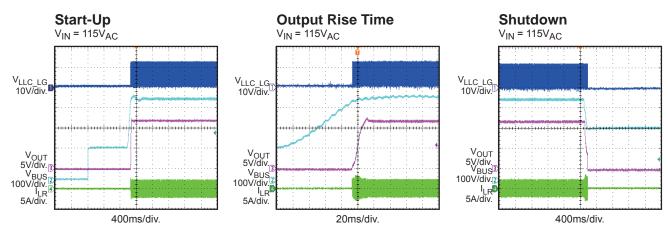
Output Ripple

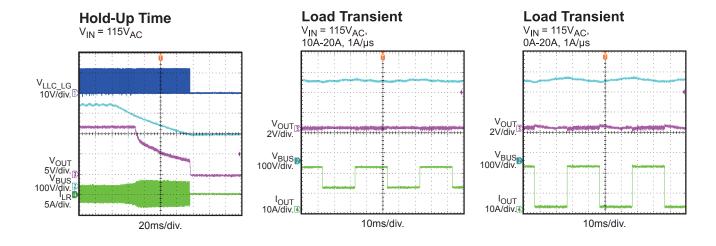


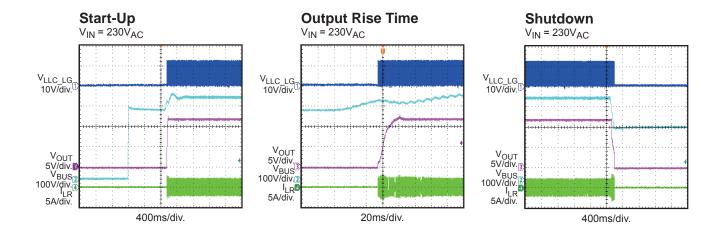


EVB TEST RESULTS (continued)

Performance waveforms are tested on the evaluation board. V_{IN_AC} = 90V to 265V, V_{OUT} = 12V, I_{OUT} = 20A, P_{OUT} = 240W



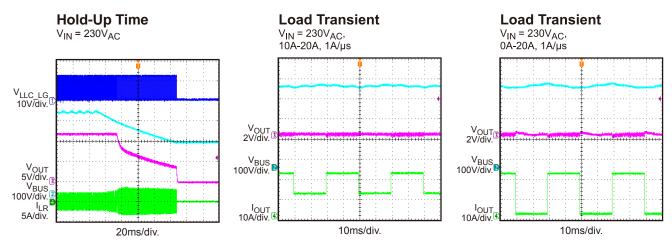


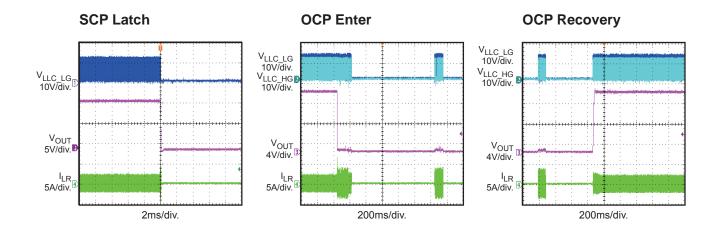




EVB TEST RESULTS (continued)

Performance waveforms are tested on the evaluation board. $V_{IN_AC} = 90V$ to 265V, $V_{OUT} = 12V$, $I_{OUT} = 20A$, $P_{OUT} = 240W$







PCB LAYOUT

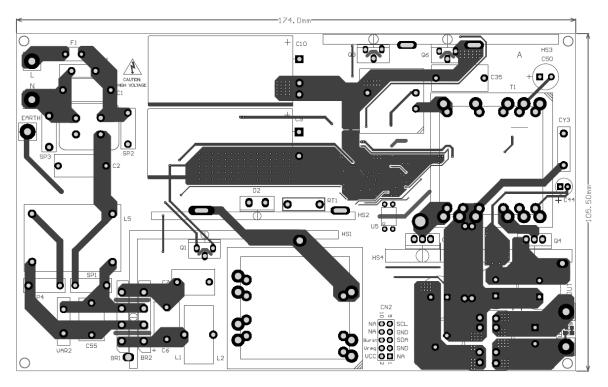


Figure 1: Top Layer

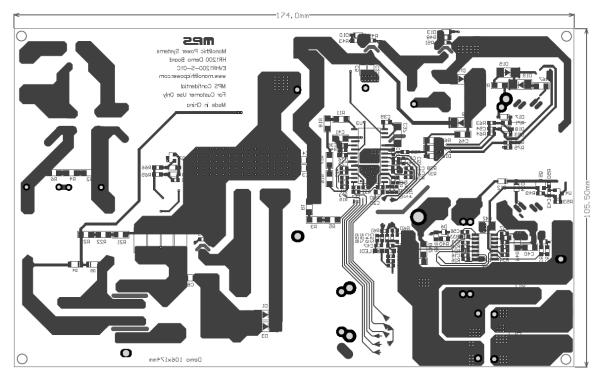


Figure 2: Bottom Layer



SURGE TEST

Line-to-line 4kV and line-to-power earth 4kV surge testing was completed according to EN61000-4-5 Level 4.

The input voltage was set at $220V_{AC}/50Hz$. The output was loaded at full load, and operation was verified following each surge event (see Table 1).

	g					
Surge Level (V)	Input Voltage (V _{AC})	Injection Location	Injection Phase (°)	Test Result (Pass/Fail)		
4000	220	L to N	90	Pass		
-4000	220	L to N	270	Pass		
4000	220	L to PE	90	Pass		
-4000	220	L to PE	270	Pass		
4000	220	N to PE	90	Pass		
-4000	220	N to PE	270	Pass		

Table 1: Surge Test Results

CONDUCTED EMI TEST

Figure 3 shows the test with a 115V_{AC} input and full-load condition.

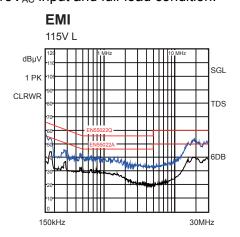


Figure 3: 115V_{AC}, 60Hz, Maximum Load, EN55022 Limits

Figure 4 shows the test with a 230V_{AC} input and full-load condition.

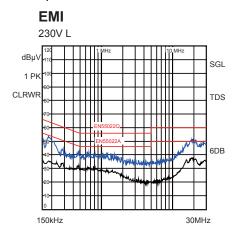
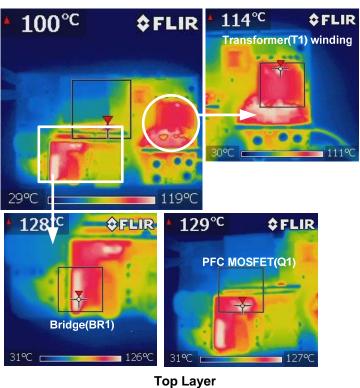


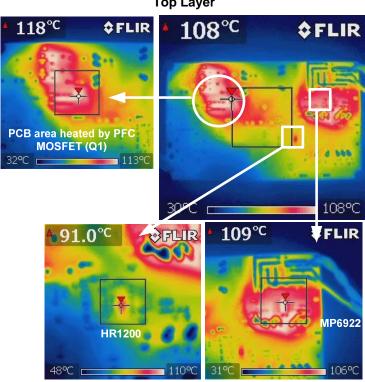
Figure 4: 230V_{AC}, 50Hz, Maximum Load, EN55022 Limits



THERMAL TEST

Figure 5 shows the test with 90V_{AC} input and full-load condition. The PCB layout is with 2oz copper. The ambient temperature is 33°C without air flow.





Bottom Layer Figure 5: Temperature Chamber Test



QUICK-START GUIDE

To quick start the EVB, follow the steps below.

- 1. Pre-set the power supply to $90V_{AC} \le V_{IN} \le 265V_{AC}$.
- 2. Turn the power supply off.
- 3. Connect the line and neutral terminals of the power supply output to the L and N ports. For three-wire input applications, connect the earth terminal to the earth port.
- 4. Connect the positive (+) load to VOUT.
- 5. Connect the negative (-) load to GND.
- 6. Turn the power supply on after making the connections.
- 7. Discharge the bulk capacitor for safety consideration after power-off.

CONTACT INFORMATION

To request this evaluation board, please refer to your local sales office: http://www.monolithicpower.com/Company/Contact-Us

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Inclusion of MPS products in critical applications is understood to be fully at the risk of the customer. Questions concerning potential risk applications should be directed to MPS.

MPS semiconductors are typically used in power supplies in which high voltages are present during operation. High-voltage safety precautions should be observed in design and operation to minimize the chance of injury.

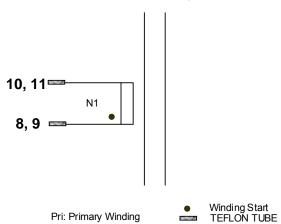
REVISION HISTORY

Date	Author	Revision	Description & Changes	Reviewed



APPENDIX 1: PFC INDUCTOR SPECIFICATION

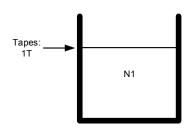
Electrical Diagram

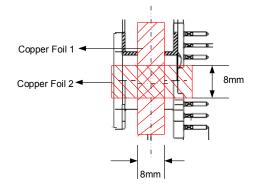


Pin Definition of Bobbin

View from the Top

Winding Diagram





Note: Core is wrapped with copper foils, as shown above. Connect the foils to pin 4 of the bobbin with wires.

Table 2: Electrical Characteristic

Parameter	Condition	Value
Primary inductance	L (8, 9-10, 11)	260µH ±10%
Core		PQ3230
Bobbin		PQ3230
Core material		DMR40 or equivalent
Turn ratio	N1	

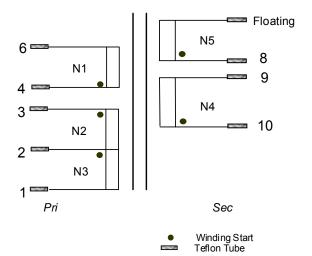
Table 3: Winding Specification

Tape Turns	Winding No.	Margin Tapes	Start and End	Wire Diameter (mm)	Turns
1	N1		8, 9→10, 11	0.1x100	30



APPENDIX 2: LLC TRANSFORMER SPECIFICATION

Electrical Diagram



Winding Diagram

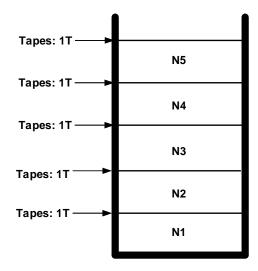


Table 4: Electrical Characteristic

Pin Definition of Bobbin

Pin Out	
	12 🔘
	11 🔿
	10 🔾
	9 🔿
	8 🔾
	7 🔿
	Pin Out

View from the Top

Parameter Condition Value Primary L_P (4-6) 0.55mH ±5% inductance PQ3230 Core Bobbin PQ3230 DMR44 or Core material equivalent 48:5:5:3:3 Turn ratio N1:N2:N3:N4:N5

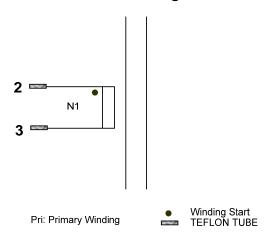
Table 5: Winding Specification

Tape Turns	Winding No.	Margin Tapes	Start and End	Wire Diameter (mm)	Turns
1	N1		4→6	0.1x30	48
1	N2		3→2	0.2x3	5
1	N3		2→1	0.2x3	5
1	N4		8→floating	0.1x100	3
1	N5		10→9	0.1x100	3

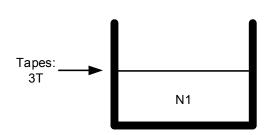


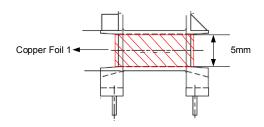
APPENDIX 3: LLC RESONANT INDUCTOR SPECIFICATION

Electrical Diagram



Winding Diagram





Pin Definition of Bobbin

Pin Out \bigcirc 1 8 🔾 ○ 2 \odot \bigcirc 3 6 🗘 \bigcirc 4 5 🗘

View from the Top

Note: Core is wrapped with copper foil, as shown above. Connect the foils to pin 6 of the bobbin with wires.

Table 6: Electrical Characteristic

rable of Electrical Characteristic				
Parameter	Condition	Value		
Primary inductance	L (2-3)	80μH ±5%		
Core		EE20/10/6		
Bobbin		EE20/10/6		
Core material		DMR40 or equivalent		
Turn ratio	N1	40		

Table 7: Winding Specification

Tape Turns	Winding No.	Margin Tapes	Start and End	Wire Diameter (mm)	Turns
3	N1		2→3	0.1x30	40

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